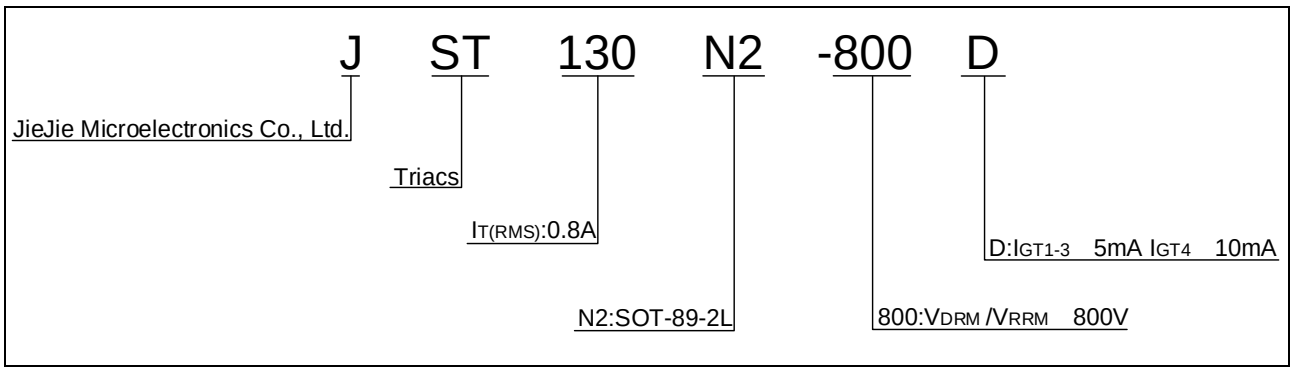
JST130N2--

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value	Unit
I_{GT}	V_D=12V R_L=33Ω	- -	5 MAX.	mA =y678.3-4 1 r

ORDERING INFORMATION



MARKING

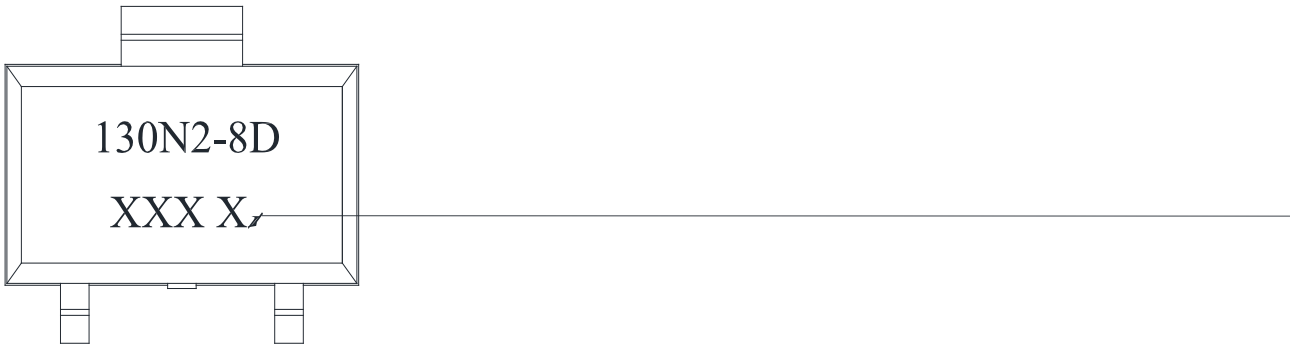


FIG.1: Maximum power dissipation versus RMS on-state current

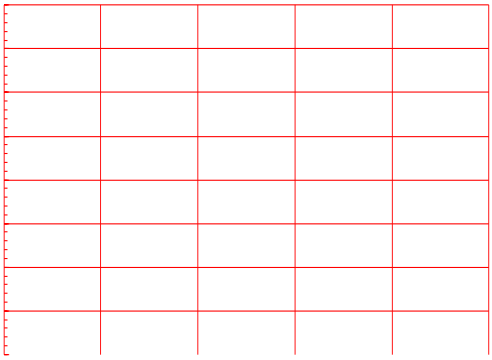
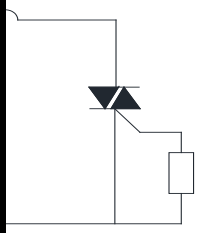


FIG.2: RMS on-state current versus case temperature

FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

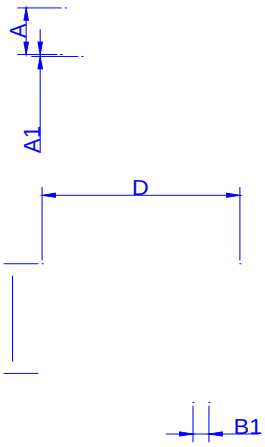


ORDERING INFORMATION

Order code	[redacted] V_{DRM}/V_{RRM} (V)	IGT(mA)	Package

[redacted]

PACKAGE MECHANICAL DATA



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